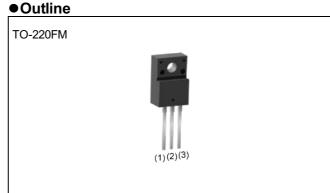


Nch 600V 95mohm(typ.) Power MOSFET

| V <sub>DSS</sub> (@Tj max.) <sup>*5</sup> | 650V   |
|---|--------|
| R <sub>DS(on)</sub> (Max.)                | 0.114Ω |
| I <sub>DP</sub> *2                        | ±105A  |
| P <sub>D</sub>                            | 81W    |



#### Features

- 1) Fast reverse recovery time (trr)
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Drive circuits can be simple
- 5) Pb-free plating ; RoHS compliant
- 6) Halogen free mold compound

# Inner circuit (2) (1) Gate (2) (1) O (1)

#### Application

Switching applications

Marking R6035VNX

#### • Absolute maximum ratings (T<sub>a</sub> = 25°C, unless otherwise specified)

| Parameter  | Symbol              | Value       | Unit |
|--|---------------------|-------------|------|
| Drain - Source voltage                           | V <sub>DSS</sub>    | 600         | V    |
| Continuous drain current ( $T_c = 25^{\circ}C$ ) | ا <sub>D</sub> *1   | ±17         | А    |
| Pulsed drain current                             | ۱ <sub>DP</sub> *2  | ±105        | А    |
| Gate - Source voltage                            | V <sub>GSS</sub>    | ±30         | V    |
| Avalanche current, single pulse                  | I <sub>AS</sub> *3  | 2.3         | А    |
| Avalanche energy, single pulse                   | E <sub>AS</sub> *3  | 148         | mJ   |
| MOSFET dv/dt                                     | dv/dt <sup>*4</sup> | 120         | V/ns |
| Power dissipation $(T_c = 25^{\circ}C)$          | P <sub>D</sub>      | 81          | W    |
| Junction temperature                             | Tj                  | 150         | °C   |
| Operating junction and storage temperature range | T <sub>stg</sub>    | -55 to +150 | °C   |

#### •Thermal resistance

| Deremeter                                    | Cumph of          | Values |      |      | l loit |
|--|-------------------|--------|------|------|--------|
| Parameter                                    | Symbol            | Min.   | Тур. | Max. | Unit   |
| Thermal resistance, junction - case          | R <sub>thJC</sub> | -      | -    | 1.54 | °C/W   |
| Thermal resistance, junction - ambient       | R <sub>thJA</sub> | -      | -    | 62.5 | °C/W   |
| Soldering temperature, wavesoldering for 10s | T <sub>sold</sub> | -      | -    | 265  | °C     |

## •Electrical characteristics (T<sub>a</sub> = 25°C)

| Deremeter                           | Currence of          | Conditions                                   | Values |       |       | Unit |  |
|-------------------------------------|----------------------|--|--------|-------|-------|------|--|
| Parameter                           | Symbol               | Conditions                                   | Min.   | Тур.  | Max.  | Unit |  |
| Drain - Source breakdown<br>voltage | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA   | 600    | -     | -     | V    |  |
| Zero gate voltage<br>drain current  | I <sub>DSS</sub>     | V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V | -      | -     | 100   | μA   |  |
| Gate - Source leakage current       | I <sub>GSS</sub>     | $V_{GS}$ = ±30V, $V_{DS}$ = 0V               | -      | -     | ±100  | nA   |  |
| Gate threshold voltage              | V <sub>GS(th)</sub>  | $V_{DS} = V_{GS}, I_D = 1.1 \text{mA}$       | 4.5    | 5.5   | 6.5   | V    |  |
| Static drain - source               | D *5                 | V <sub>GS</sub> = 15V, I <sub>D</sub> = 8A   | -      | 0.095 | 0.114 | Ω    |  |
| on - state resistance               | ${R}_{DS(on)}^{*5}$  | V <sub>GS</sub> = 10V, I <sub>D</sub> = 8A   | -      | 0.099 | 0.119 | Ω    |  |
| Gate resistance                     | R <sub>G</sub>       | f = 1MHz, open drain                         | -      | 1.7   | -     | Ω    |  |



# •Electrical characteristics (T<sub>a</sub> = 25°C)

| Deremeter                                   | Cumph of               | Conditions                                   | Values |      |      | Unit |  |
|---|------------------------|--|--------|------|------|------|--|
| Parameter                                   | Symbol                 | Conditions                                   | Min.   | Тур. | Max. | Unit |  |
| Input capacitance                           | C <sub>iss</sub>       | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 100V | -      | 2400 | -    |      |  |
| Output capacitance                          | C <sub>oss</sub>       | f = 100kHz                                   | -      | 80   | -    |      |  |
| Effective output capacitance energy related | C <sub>o(er)</sub> *6  | V <sub>GS</sub> = 0V                         | -      | 80   | -    | pF   |  |
| Effective output capacitance time related   | C <sub>o(tr)</sub> *7  | $V_{DS} = 0V$ to 480V                        | -      | 490  | -    |      |  |
| Turn - on delay time                        | t <sub>d(on)</sub> *5  | $V_{DD} \simeq 300$ V, $V_{GS}$ = 15V        | -      | 34   | -    |      |  |
| Rise time                                   | t <sub>r</sub> *5      | I <sub>D</sub> = 8A                          | -      | 18   | -    | 20   |  |
| Turn - off delay time                       | t <sub>d(off)</sub> *5 | R <sub>L</sub> ≃ 37.5Ω                       | -      | 81   | -    | ns   |  |
| Fall time                                   | t <sub>f</sub> *5      | R <sub>G</sub> = 10Ω                         | -      | 10   | -    |      |  |

### • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

| Deremeter            | Cumph of               | Conditions                                 | Values |      |      | Linit |
|----------------------|------------------------|--|--------|------|------|-------|
| Parameter            | Symbol Conditions      |  | Min.   | Тур. | Max. | Unit  |
| Total gate charge    | $Q_g^{*5}$             | $V_{DD} \simeq 300 V$                      | -      | 50   | -    |       |
| Gate - Source charge | Q <sub>gs</sub> *5     | I <sub>D</sub> = 8A                        | -      | 20   | -    | nC    |
| Gate - Drain charge  | Q <sub>gd</sub> *5     | V <sub>GS</sub> = 10V                      | -      | 22   | -    |       |
| Gate plateau voltage | V <sub>(plateau)</sub> | $V_{DD} \simeq 300$ V, I <sub>D</sub> = 8A | -      | 8.3  | -    | V     |



| • Body diode electrical characteristics | (Source-Drain) ( $T_a = 25^{\circ}C$ ) |
|---|--|
|---|--|

| Parameter                     | Symbol             | Conditions                                | Values |     |      | Unit |  |
|-------------------------------|--------------------|---|--------|-----|------|------|--|
| Parameter                     | Symbol             | Conditions                                | Min.   |     | Max. | Unit |  |
| Source current                | ۱ <sub>S</sub> *1  | • T <sub>C</sub> = 25°C                   | -      | -   | 17   | А    |  |
| Pulsed source current         | $I_{SP}^{*2}$      | 1 <sub>C</sub> - 25 C                     | -      | -   | 105  | А    |  |
| Source-Drain voltage          | $V_{SD}^{*5}$      | V <sub>GS</sub> = 0V, I <sub>S</sub> = 8A | -      | -   | 1.5  | V    |  |
| Reverse recovery time         | t <sub>rr</sub> *5 | - V <sub>DD</sub>                         | -      | 92  | -    | ns   |  |
| Reverse recovery charge       | Q <sub>rr</sub> *5 | I <sub>S</sub> = 8A                       | -      | 391 | -    | nC   |  |
| Peak reverse recovery current | ۱ <sub>m</sub> *5  | di/dt = 100A/µs                           | -      | 8.3 | -    | А    |  |

\*1 Limited only by maximum temperature allowed.

\*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

\*3 L  $\simeq$  50mH, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , starting T<sub>i</sub> = 25°C

- \*4  $V_{DS}$  = 0 to 400V
- \*5 Pulsed
- \*6 Co(er) is a fixed capacitance that gives the same stored energy as Coss while  $V_{DS}$  is rising from 0 to 80%  $V_{DSS}$ .
- \*7 Co(tr) is a fixed capacitance that gives the same charging time as Coss while  $V_{DS}$  is rising from 0 to 80%  $V_{DSS}$ .



#### •Electrical characteristic curves

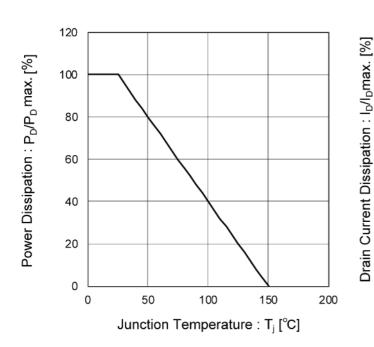


Fig.1 Power Dissipation Derating Curve

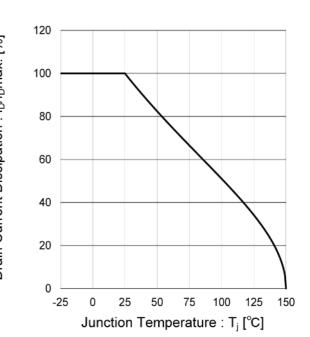
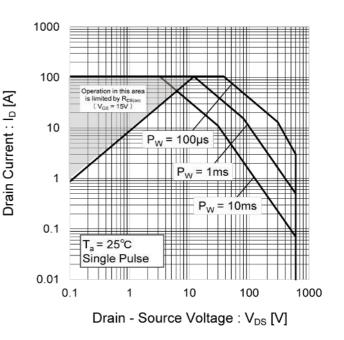


Fig.2 Drain Current Derating Curve

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

10 Normalized Transient Thermal Resistance : r(t) T<sub>a</sub> = 25°C Single Pulse  $R_{th(ch-c)(t)} = r_{(t)} \times R_{th(ch-c)}$ R<sub>th(ch-c)</sub> = 1.54°C/W 1 0.1 top D = 1D = 0.5 D = 0.1 D = 0.05 D = 0.01 D = Single 0.01 0.0001 0.001 0.01 0.1 1 10 Pulse Width : Pw [s]

Fig.4 Maximum Safe Operating Area





#### • Electrical characteristic curves

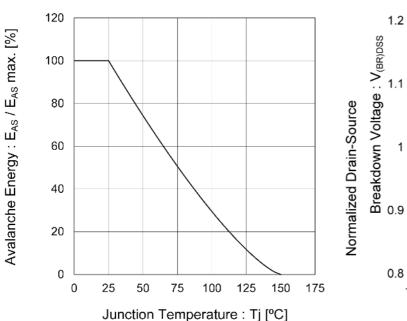


Fig.5 Avalanche Energy Derating Curve

#### Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

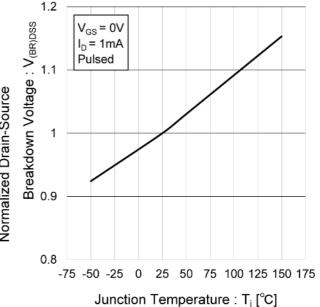


Fig.7 Output Characteristics(I)



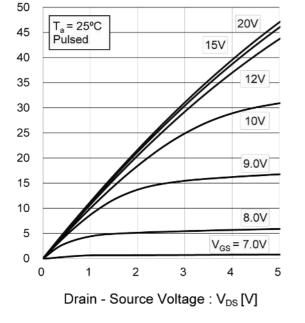
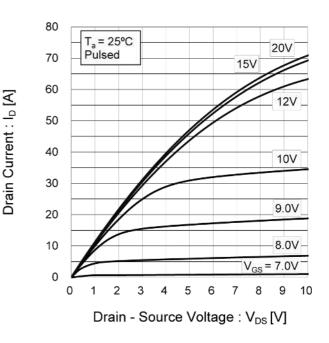


Fig.8 Output Characteristics(II)



6/11

#### • Electrical characteristic curves

vs. Drain current

Fig.9 Gate Threshold Voltage



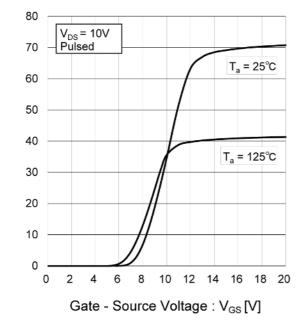
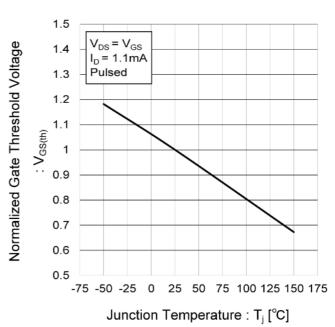
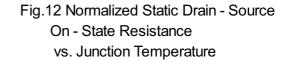
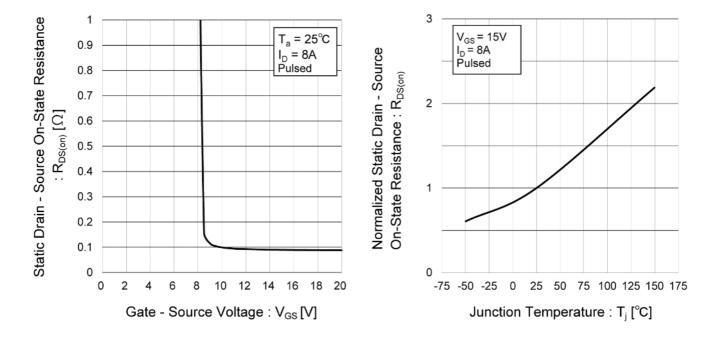


Fig.11 Static Drain - Source On - State Resistance vs. Gate Source Voltage



#### Fig.10 Normalized Gate Threshold . Voltage vs Junction Temperature





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#### Electrical characteristic curves

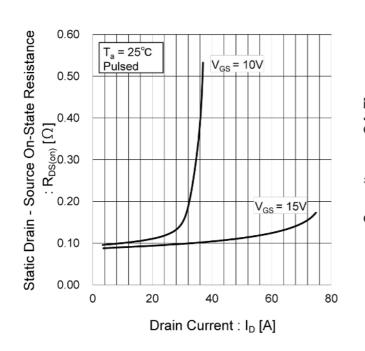


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current Fig.14 Capacitances

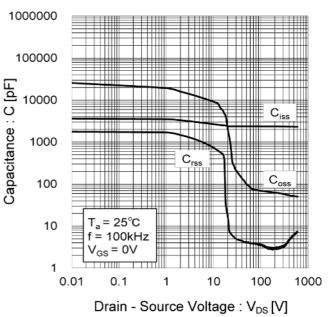


Fig.15 Coss Stored Energy

Fig.16 Gate Charge

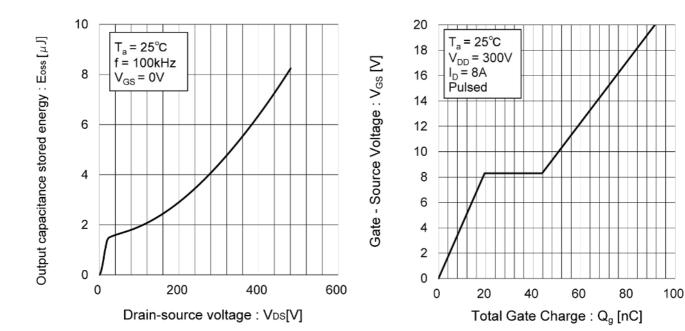




Fig.18 Reverse Recovery Time vs. Source Current

#### • Electrical characteristic curves

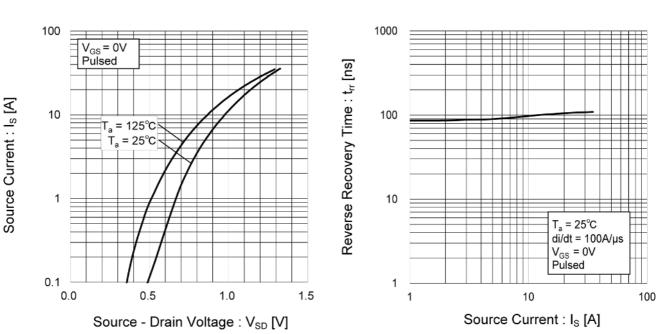


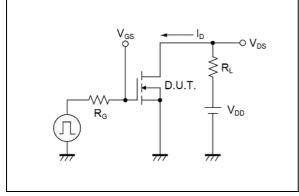
Fig.17 Source Current vs. Source - Drain Voltage

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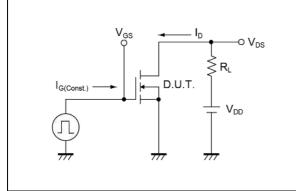


#### Measurement circuits





#### Fig.2-1 Gate Charge Measurement Circuit



#### Fig.3-1 Avalanche Measurement Circuit

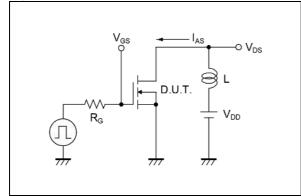
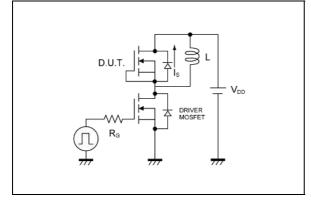
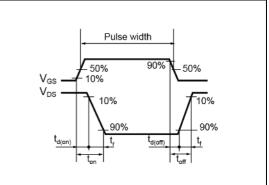


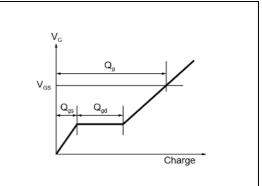
Fig.4-1 Diode Recovery Measurement Circuit



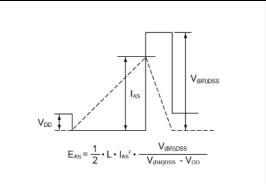
#### Fig.1-2 Switching Waveforms



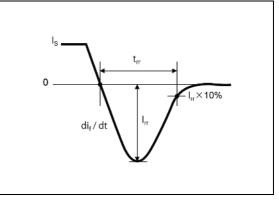
#### Fig.2-2 Gate Charge Waveform



#### Fig.3-2 Avalanche Waveform



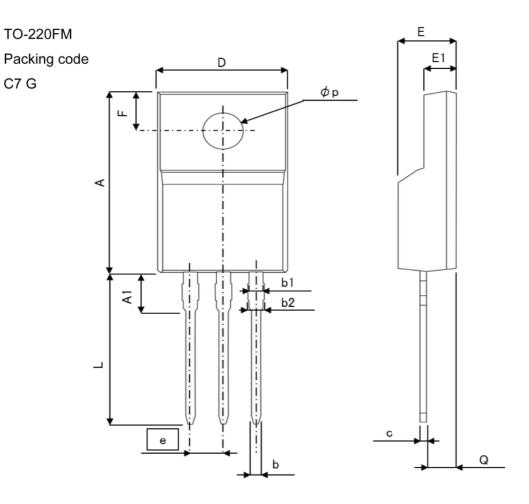
#### Fig.4-2 Diode Recovery Waveform



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#### Dimensions



| DIM | MILIM | ETERS | INC   | HES   |
|-----|-------|-------|-------|-------|
| DIM | MIN   | MAX   | MIN   | MAX   |
| А   | 15.67 | 16.27 | 0.617 | 0.641 |
| A1  | 3.03  | 3.43  | 0.119 | 0.135 |
| b   | 0.70  | 0.95  | 0.028 | 0.037 |
| b1  | 1.00  | 1.40  | 0.039 | 0.055 |
| b2  | 1.10  | 1.50  | 0.043 | 0.059 |
| с   | 0.45  | 0.65  | 0.018 | 0.026 |
| D   | 9.90  | 10.30 | 0.390 | 0.406 |
| E   | 4.60  | 5.00  | 0.181 | 0.197 |
| E1  | 2.44  | 2.74  | 0.096 | 0.108 |
| е   | 2.    | 2.54  |       | 00    |
| F   | 3.10  | 3.50  | 0.122 | 0.138 |
| L   | 12.6  | 13.6  | 0.946 | 0.535 |
| р   | 2.98  | 3.38  | 0.117 | 0.133 |
| Q   | 2.25  | 3.25  | 0.089 | 0.128 |

Dimension in mm/inches



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|---|
|---|

| JAPAN  | USA     | EU         | CHINA   |
|--------|---------|------------|---------|
| CLASSⅢ | CLASSⅢ  | CLASS II b | CLASSII |
| CLASSⅣ | CLASSII | CLASSⅢ     | CLASSI  |

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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